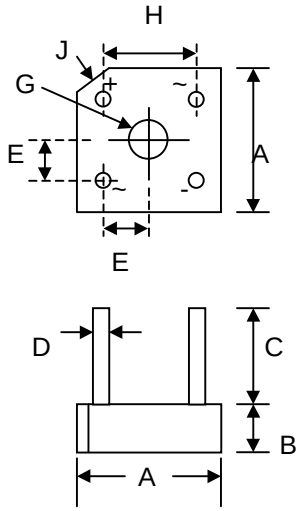
KBPC800G – KBPC810G

8.0A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- High Current Capability
- High Case Dielectric Strength
- High Surge Current Capability
- Ideal for Printed Circuit Board Application
- Plastic Material has Underwriters Laboratory Flammability Classification 94V-O



KBPC-8		
Dim	**Min**	**Max**
A	18.54	19.56
B	6.35	7.60
C	19.00	—
D	1.27 Ø Typical	
E	5.33	7.37
G	Hole for #6 screw	
	3.60	4.00
H	12.20	13.20
J	2.38 x 45°C Typical	
All Dimensions in mm		

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Marked on Body
- Weight: 5.4 grams (approx.)
- Mounting Position: Through Hole for #6 Screw
- Mounting Torque: 5.0 Inch-pounds Maximum
- Marking: Type Number

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	KBPC 800G	KPBC 801G	KBPC 802G	KBPC 804G	KBPC 806G	KBPC 808G	KBPC 810G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T_A = 50°C	I_O	8.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	160							A
Forward Voltage (per element) @I_F = 4.0A	V_{FM}	1.1							V
Peak Reverse Current @T_C = 25°C At Rated DC Blocking Voltage @T_C = 125°C	I_R	5.0 500							µA
I^2t Rating for Fusing (t<8.3ms) (Note 2)	I^2t	160							A^2s
Typical Junction Capacitance (Note 3)	C_j	200							pF
Typical Thermal Resistance (Note 4)	$R_{\theta JC}$	6.0							K/W
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150							°C

Note: 1. Mounted on 8.6" sq. x 0.24" thick Al. plate.
2. Non-repetitive, for t > 1ms and < 8.3ms.
3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
4. Thermal resistance junction to case per element.

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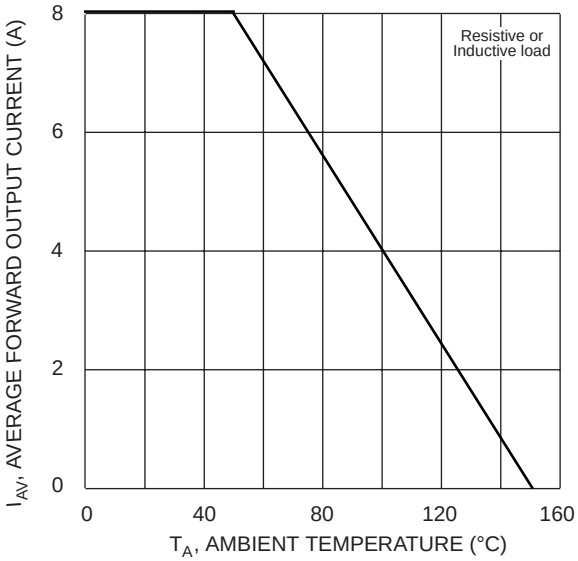


Fig. 1 Forward Current Derating Curve

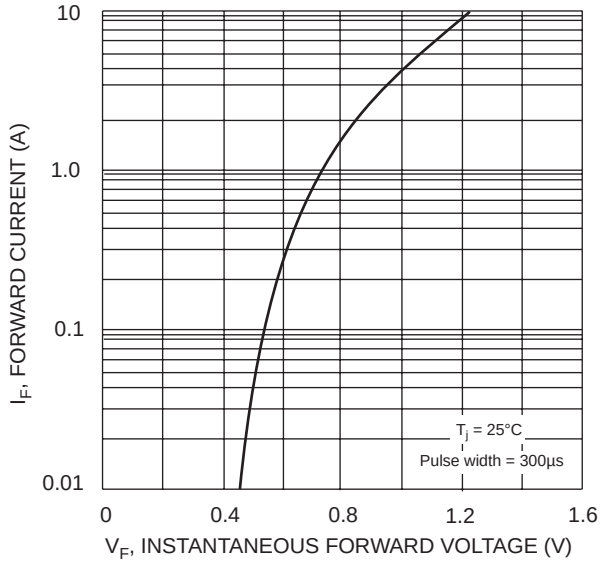


Fig. 2 Typical Forward Characteristics, per element

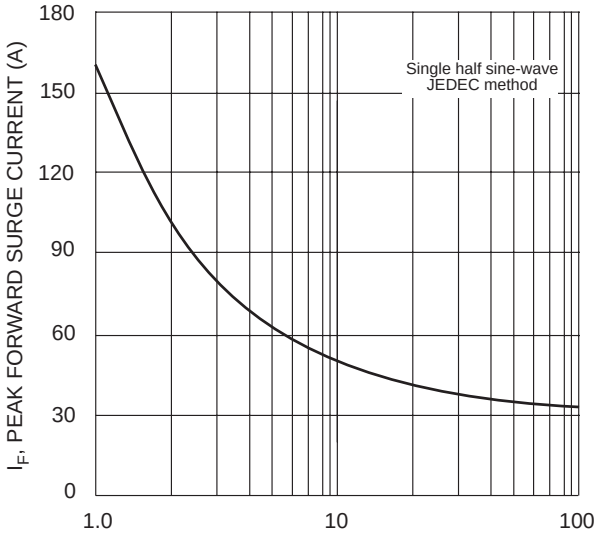


Fig. 3 Forward Surge Current

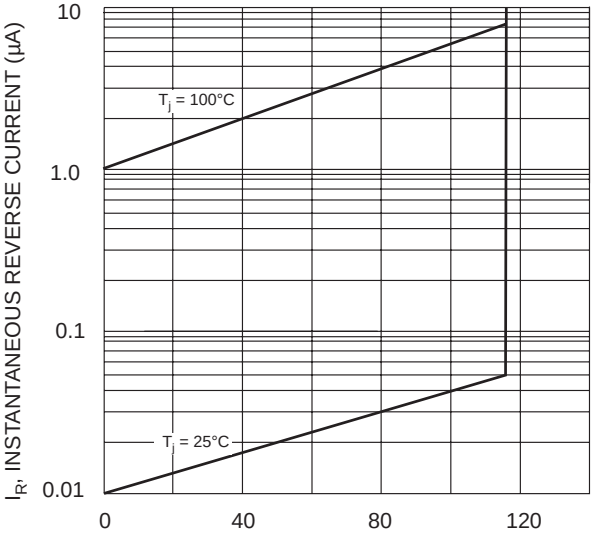


Fig. 4 Typical Reverse Characteristics, per element

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ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
KBPC800G	Square Bridge	200 Units/Box
KBPC801G	Square Bridge	200 Units/Box
KBPC802G	Square Bridge	200 Units/Box
KBPC804G	Square Bridge	200 Units/Box
KBPC806G	Square Bridge	200 Units/Box
KBPC808G	Square Bridge	200 Units/Box
KBPC810G	Square Bridge	200 Units/Box

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

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